

NCS1002A

Constant Voltage / Constant Current Secondary-Side Controller

Description

The NCS1002A is a performance upgrade from the NCS1002 focused on reducing power consumption in applications that require more efficient operation. It is a highly integrated solution for Switching Mode Power Supply (SMPS) applications requiring a dual control loop to perform Constant Voltage (CV) and Constant Current (CC) regulation. The NCS1002A integrates a 2.5 V voltage reference and two precision op amps. The voltage reference, along with Op Amp 1, is the core of the voltage control-loop. Op Amp 2 is an independent, uncommitted amplifier specifically designed for the current control. Key external components needed to complete the two control loops are: (a) A resistor divider that senses the output of the power supply (battery charger) and fixes the voltage regulation set point at the specified value. (b) A sense resistor that feeds the current sensing circuit with a voltage proportional to the DC output current. This resistor determines the current regulation set point and must be adequately rated in terms of power dissipation. The NCS1002A comes in a small 8-pin SOIC package and is ideal for space-shrunk applications such as battery chargers.

Features

- Low Input Offset Voltage: 0.5 mV, Typ
- Input Common-Mode Range includes Ground
- Low Quiescent Current: 150 μ A per Op Amp at $V_{CC} = 5$ V
- Large Output Voltage Swing
- Wide Power Supply Range: 3 V to 32 V
- High ESD Protection: 2 kV
- These are Pb-Free Devices

Typical Applications

- Battery Chargers
- Switch Mode Power Supplies



ON Semiconductor®

<http://onsemi.com>

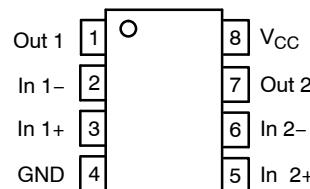
MARKING DIAGRAMS



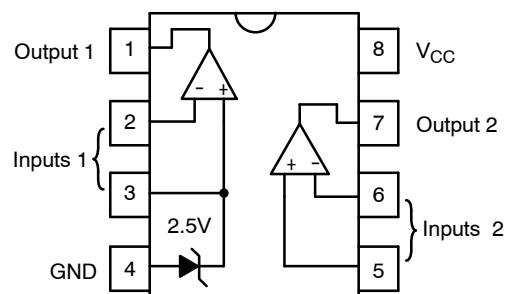
A = Assembly Location
L = Wafer Lot
Y = Year
W = Work Week
■ = Pb-Free Package

(Note: Microdot may be in either location)

PIN CONNECTIONS



(Top View)



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 8 of this data sheet.

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MAXIMUM RATINGS

| Parameter | Symbol | Rating | Unit |
|--|------------|-------------|------|
| Supply Voltage (V_{CC} to GND) | V_{CC} | 36 | V |
| Differential Input Voltage | V_{id} | 36 | V |
| Input Voltage | V_i | -0.3 to +36 | V |
| ESD Protection Voltage at Pin Human Body Model | V_{ESD} | 2000 | V |
| Maximum Junction Temperature | T_J | 150 | °C |
| Specification Temperature Range (T_{min} to T_{max}) | T_A | -40 to +105 | °C |
| Operating Free-Air Temperature Range | T_{oper} | -55 to +125 | °C |
| Storage Temperature Range | T_{stg} | -55 to +150 | °C |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

THERMAL CHARACTERISTICS

| Parameter | Symbol | Rating | Unit |
|---|-----------------|--------|------|
| Thermal Resistance Junction-to-Ambient | $R_{\theta JA}$ | 175 | °C/W |

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ELECTRICAL CHARACTERISTICS

| Symbol | Characteristics | Conditions | Min | Typ | Max | Unit |
|-----------------|---|------------|-----|------|------|------|
| I _{CC} | Total Supply Current, excluding current in the Voltage Reference V _{CC} = 5 V, no load; -40 ≤ T _A ≤ +105°C | | | 0.15 | 0.25 | mA |
| I _{CC} | Total Supply Current, excluding Current in the Voltage Reference V _{CC} = 30 V, no load; -40 ≤ T _A ≤ +105°C | | | 0.2 | 0.3 | mA |

OP AMP 1 (OP AMP WITH NONINVERTING INPUT CONNECTED TO THE INTERNAL V_{ref})

(V_{CC} = 5 V, T_A = 25°C unless otherwise noted)

| | | | | | | |
|---------------------|---|---|-----|------|-----|-------|
| V _{IO} | Input Offset Voltage | T _A = 25°C | | | 2.0 | mV |
| | | -40 ≤ T _A ≤ +105°C | | | 3.0 | mV |
| DV _{IO} | Input Offset Voltage Drift (-40 ≤ T _A ≤ +105°C) | | | | 7.0 | µV/°C |
| I _{IB} | Input Bias Current (Inverting Input Only) | | | 20 | 150 | nA |
| AVD | Large Signal Voltage Gain (V _{CC} = 15 V, R _L = 2 kΩ, V _{ICM} = 0 V) | | | 100 | | V/mV |
| PSRR | Power Supply Rejection (V _{CC} = 5.0 V to 30 V, V _{OUT} = 2 V) | | 80 | 100 | | dB |
| I _{SOURCE} | Output Source Current (V _{CC} = 15 V, V _{OUT} = 2.0 V, V _{id} = 1 V) | | 20 | 40 | | mA |
| I _O | Short Circuit to GND (V _{CC} = 15 V) | | | 40 | 60 | mA |
| I _{SINK} | Output Current Sink (V _{id} = -1 V) | V _{CC} = +15 V, V _{OUT} = 0.2 V (Note 1) | 1 | 10 | | mA |
| | | V _{CC} = +15 V, V _{OUT} = 2 V | 10 | 20 | | mA |
| V _{OH} | Output Voltage Swing, High (V _{CC} = 30 V) | R _L = 2 kΩ, T _A = 25°C | 26 | 27 | | V |
| | | -40 ≤ T _A ≤ +105°C | 26 | | | |
| | | R _L = 10 kΩ, T _A = 25°C | 27 | 28 | | |
| | | -40 ≤ T _A ≤ +105°C | 27 | | | |
| V _{OL} | Output Voltage Swing, Low | R _L = 10 kΩ, T _A = 25°C | | 5.0 | 50 | mV |
| SR | Slew Rate (AV = +1, V _i = 0.5 V to 2 V, V _{CC} = 15 V, R _L = 2 kΩ, C _L = 100 pF) | | 0.2 | 0.4 | | V/µs |
| GBP | Gain Bandwidth Product (V _{CC} = 30 V, AV = +1, (Note 1) R _L = 2 kΩ, C _L = 100 pF, f = 100 kHz, V _{IN} = 10 mV _{PP}) | | 0.5 | 0.9 | | MHz |
| THD | Total Harmonic Distortion (f = 1 kHz, AV = 10, R _L = 2 kΩ, V _{CC} = 30 V, V _{OUT} = 2 V _{PP}) | | | 0.08 | | % |

OP AMP 2 (INDEPENDENT OP AMP) (V_{CC} = 5.0 V, T_A = 25°C unless otherwise noted)

| | | | | | | |
|------------------|---|-------------------------------|----|-----|-----|-------|
| V _{IO} | Input Offset Voltage | T _A = 25°C | | 0.5 | 2.0 | mV |
| | | -40 ≤ T _A ≤ +105°C | | | 3.0 | |
| DV _{IO} | Input Offset Voltage Drift (-40 ≤ T _A ≤ +105°C) | | | | 7.0 | µV/°C |
| I _{IO} | Input Offset Current | T _A = 25°C | | 2.0 | 75 | nA |
| | | -40 ≤ T _A ≤ +105°C | | | 150 | |
| I _B | Input Bias Current | T _A = 25°C | | 20 | 150 | nA |
| | | -40 ≤ T _A ≤ +105°C | | | 200 | |
| AVD | Large Signal Voltage Gain (V _{CC} = 15 V, R _L = 2 kΩ, V _{OUT} = 1.4 V to 11.4 V) | T _A = 25°C | 50 | 100 | | V/mV |
| | | -40 ≤ T _A ≤ +105°C | 25 | | | |
| PSRR | Power Supply Rejection (V _{CC} = 5 V to 30 V) | | 80 | 100 | | dB |

1. Guaranteed by design and/or characterization.

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ELECTRICAL CHARACTERISTICS (continued)

| Symbol | Characteristics | Conditions | Min | Typ | Max | Unit |
|--|---|---|-----|------|----------------|------------------------|
| OP AMP 2 (INDEPENDENT OP AMP) (continued) ($V_{CC} = 5.0 \text{ V}$, $T_A = 25^\circ\text{C}$ unless otherwise noted) | | | | | | |
| V_{ICM} | Input Common Mode Voltage Range (Note 2) ($V_{CC} = +30 \text{ V}$) | $T_A = 25^\circ\text{C}$ | 0 | | $V_{CC} - 1.5$ | V |
| | | $-40 \leq T_A \leq +105^\circ\text{C}$ | 0 | | $V_{CC} - 2.0$ | |
| CMRR | Common Mode Rejection Ratio (Note 4) | 0 to $V_{CC} - 1.7 \text{ V}$, $T_A = 25^\circ\text{C}$ | 70 | 85 | | dB |
| | | 0 to $V_{CC} - 2.2 \text{ V}$ $-40 \leq T_A \leq +105^\circ\text{C}$ | 60 | | | |
| I_{SOURCE} | Output Current Source ($V_{CC} = 15 \text{ V}$, $V_{OUT} = 2 \text{ V}$, $V_{ID} = +1 \text{ V}$) | | 20 | 40 | | mA |
| I_O | Short-Circuit to GND ($V_{CC} = 15 \text{ V}$) | | | 40 | 60 | mA |
| I_{SINK} | Output Current Sink ($V_{ID} = -1 \text{ V}$) | $V_{CC} = +15 \text{ V}$, $V_{OUT} = 0.2 \text{ V}$ | 1 | 10 | | mA |
| | | $V_{CC} = +15 \text{ V}$, $V_{OUT} = 2 \text{ V}$ | 10 | 20 | | mA |
| V_{OH} | Output Voltage Swing, High ($V_{CC} = 30 \text{ V}$) | $R_L = 2 \text{ k}\Omega$, $T_A = 25^\circ\text{C}$ | 26 | 27 | | V |
| | | $-40 \leq T_A \leq +105^\circ\text{C}$ | 26 | | | |
| | | $R_L = 10 \text{ k}\Omega$, $T_A = 25^\circ\text{C}$ | 27 | 28 | | |
| | | $-40 \leq T_A \leq +105^\circ\text{C}$ | 27 | | | |
| V_{OL} | Output Voltage Swing, Low | $R_L = 10 \text{ k}\Omega$, $T_A = 25^\circ\text{C}$ | | 5.0 | 50 | mV |
| SR | Slew Rate ($AV = +1$, $V_i = 0.5 \text{ V}$ to 3 V , $V_{CC} = 15 \text{ V}$, $R_L = 2 \text{ k}\Omega$, $C_L = 100 \text{ pF}$) | | 0.2 | 0.4 | | V/ μ s |
| GBP | Gain Bandwidth Product ($V_{CC} = 30 \text{ V}$, $AV = +1$, $R_L = 2 \text{ k}\Omega$, $C_L = 100 \text{ pF}$, $f = 100 \text{ kHz}$, $V_{IN} = 10 \text{ mV}_{PP}$) (Note 4) | | 0.5 | 0.9 | | MHz |
| THD | Total Harmonic Distortion ($f = 1 \text{ kHz}$, $AV = 10$, $R_L = 2 \text{ k}\Omega$, $V_{CC} = 30 \text{ V}$, $V_{OUT} = 2 \text{ V}_{PP}$) | | | 0.08 | | % |
| e_{noise} | Equivalent Input Noise Voltage ($f = 1 \text{ kHz}$, $R_S = 100 \Omega$, $V_{CC} = 30 \text{ V}$) | | | 50 | | nV/ $\sqrt{\text{Hz}}$ |

VOLTAGE REFERENCE ($V_{CC} = 5.0 \text{ V}$, $T_A = 25^\circ\text{C}$ unless otherwise noted)

| | | | | | | |
|------------------|---|--|------|-----|------|----------|
| I_K | Cathode Current | | 0.05 | | 100 | mA |
| V_{ref} | Reference Voltage ($I_K = 1 \text{ mA}$) | $T_A = 25^\circ\text{C}$ | 2.49 | 2.5 | 2.51 | V |
| | | $-40 \leq T_A \leq +105^\circ\text{C}$ | 2.48 | 2.5 | 2.52 | |
| ΔV_{ref} | Reference Deviation over Temperature ($V_{KA} = V_{ref}$, $I_K = 10 \text{ mA}$, $-40 \leq T_A \leq +105^\circ\text{C}$) (Note 4) | | | 7.0 | 30 | mV |
| I_{min} | Minimum Cathode Current for Regulation ($2.4875 V_f \leq V_{KA} \leq 2.5125 V_f$) | | | 10 | 50 | μ A |
| $ Z_{KA} $ | Dynamic Impedance (Note 3) ($V_{KA} = V_{ref}$, $I_K = 1 \text{ mA}$ to 100 mA , $f < 1 \text{ kHz}$) | | | 0.2 | 0.5 | Ω |

- The input common-mode voltage of either input signal should not be allowed to go negative by more than 0.3 V. The upper end of the common-mode range is $V_{CC} - 1.5 \text{ V}$. Both inputs can go to $V_{CC} + 0.3 \text{ V}$ without damage.
- The Dynamic Impedance is defined as $|Z_{KA}| = \Delta V_{KA} / \Delta I_K$.
- Guaranteed by design and/or characterization.

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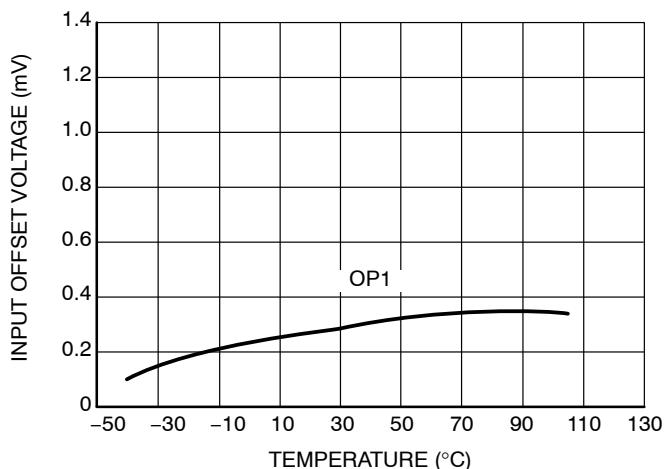


Figure 1. Input Offset Voltage vs. Temperature

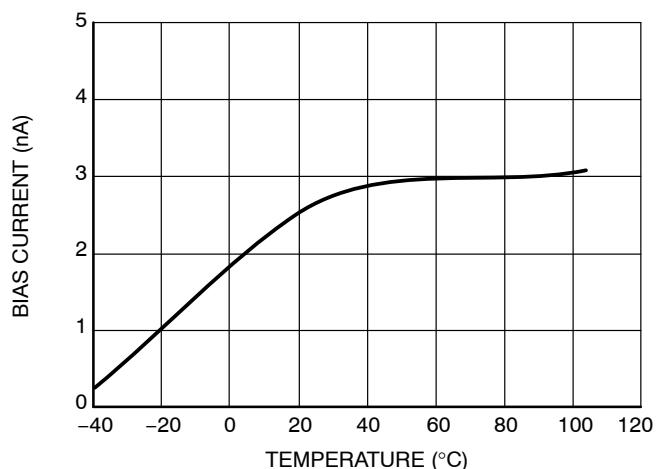


Figure 2. IB vs. Temperature

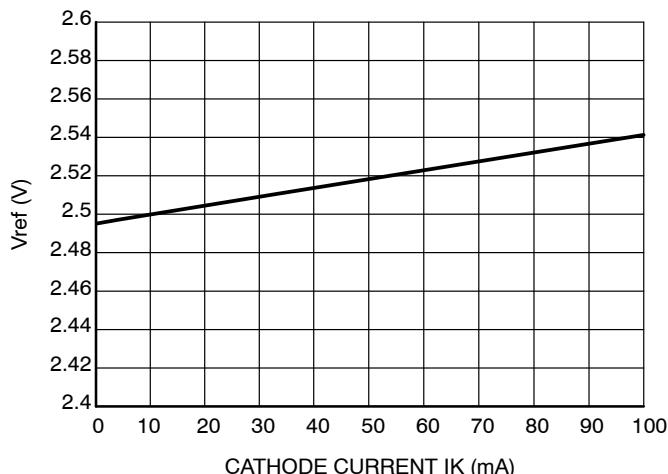


Figure 3. Vref as a Function of IK

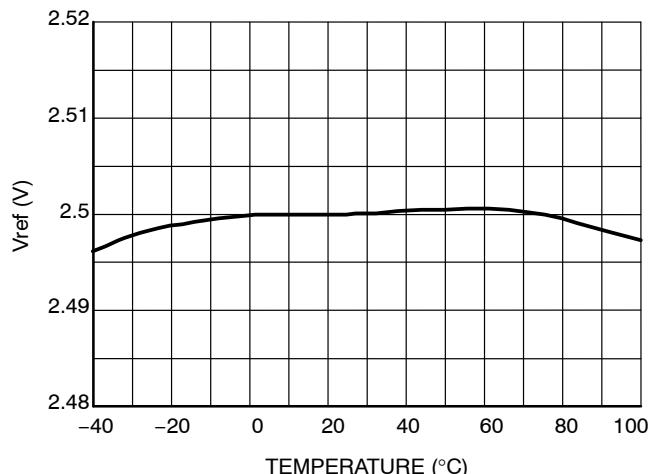


Figure 4. Vref Over Temperature

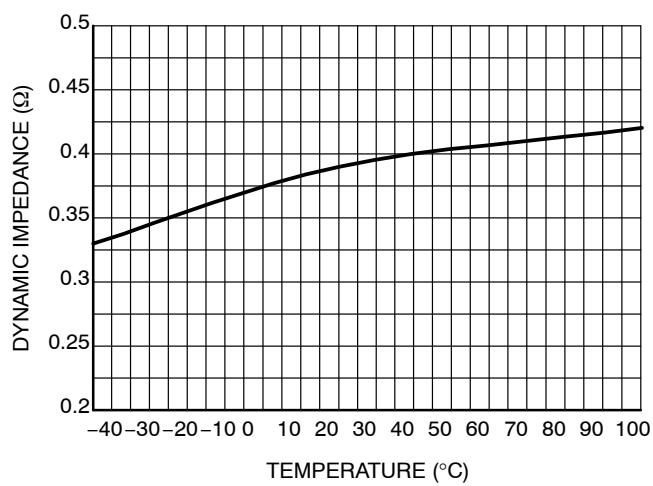


Figure 5. Ref Dynamic Impedance vs. Temperature

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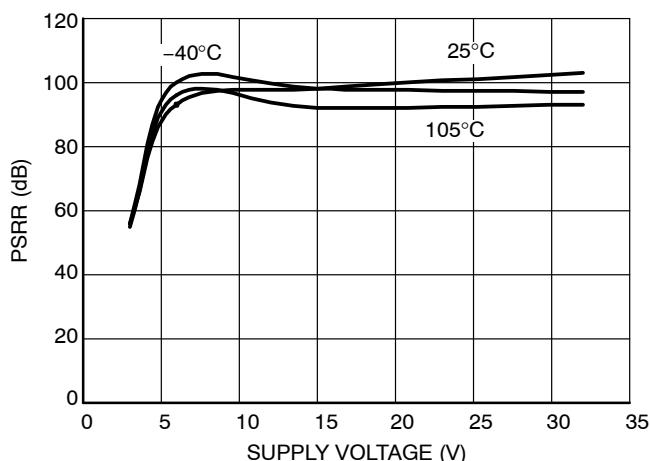


Figure 6. NCS1002A PSRR vs. Supply Voltage

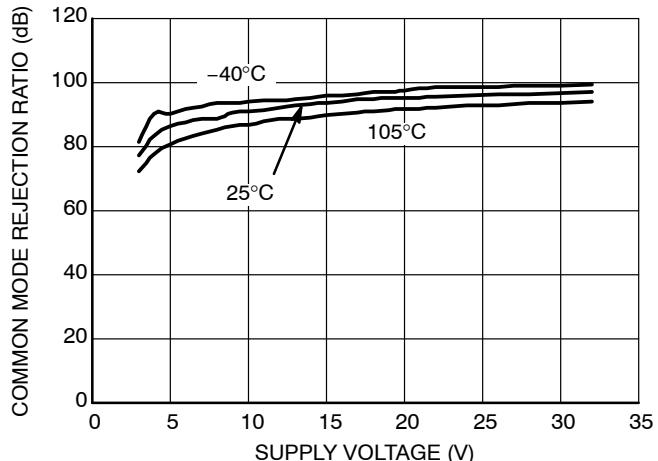


Figure 7. NCS1002A CMRR vs. Supply Voltage

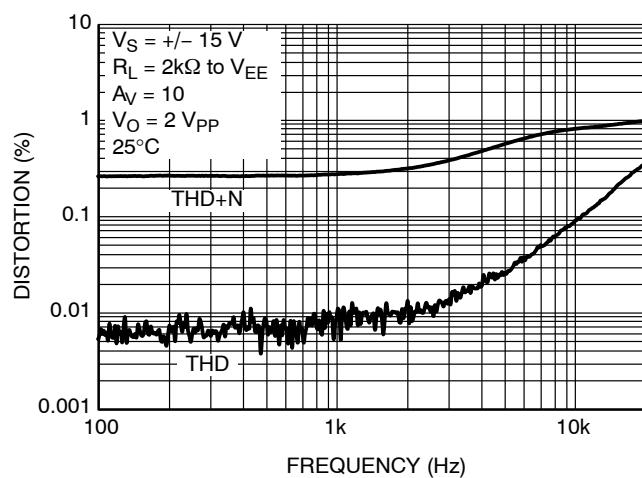


Figure 8. Distortion vs. Frequency

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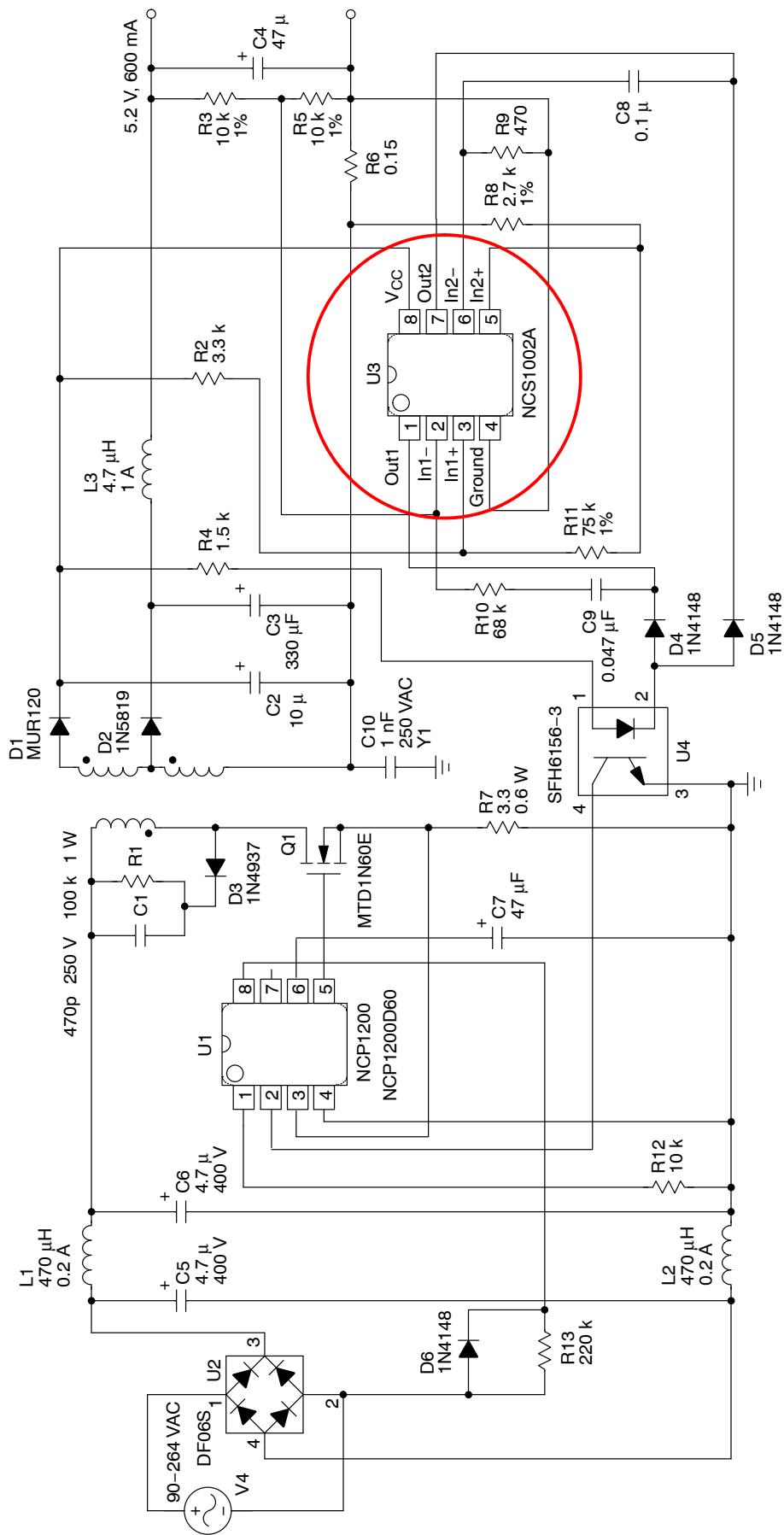


Figure 1. AC Adapter Application

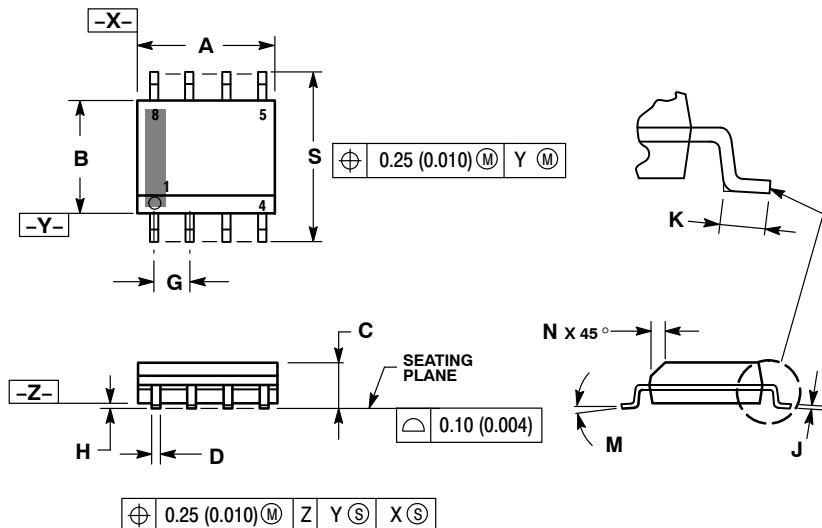
NCS1002A

ORDERING INFORMATION

| Device | Package | Shipping [†] |
|--------------|---------------------|-----------------------|
| NCS1002ADR2G | SOIC-8 (Pb-Free) | 2500 / Tape & Reel |

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

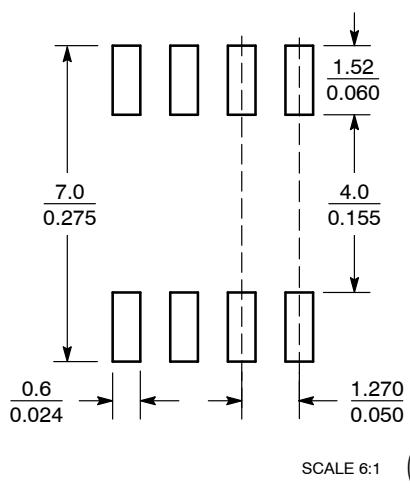
SOIC-8 NB
CASE 751-07
ISSUE AK

NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. 751-01 THRU 751-06 ARE OBSOLETE. NEW STANDARD IS 751-07.

| DIM | MILLIMETERS | | INCHES | |
|-----|-------------|------|--------|-------|
| | MIN | MAX | MIN | MAX |
| A | 4.80 | 5.00 | 0.189 | 0.197 |
| B | 3.80 | 4.00 | 0.150 | 0.157 |
| C | 1.35 | 1.75 | 0.053 | 0.069 |
| D | 0.33 | 0.51 | 0.013 | 0.020 |
| G | 1.27 | BSC | 0.050 | BSC |
| H | 0.10 | 0.25 | 0.004 | 0.010 |
| J | 0.19 | 0.25 | 0.007 | 0.010 |
| K | 0.40 | 1.27 | 0.016 | 0.050 |
| M | 0 ° | 8 ° | 0 ° | 8 ° |
| N | 0.25 | 0.50 | 0.010 | 0.020 |
| S | 5.80 | 6.20 | 0.228 | 0.244 |

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помошь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помошь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

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Факс: 8 (812) 320-02-42

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